NSN 5961-01-343-2442

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Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 reverse voltage, peak
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector absolute
Capacitance Rating In Picofarads:
69.36
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500/436 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: